## NSN 5962-01-198-7114

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Body Length:
Between 0.750 inches and 0.785 inches
Body Width:
Between 0.245 inches and 0.271 inches
Body Height:
0.204 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and 3-state output and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
13 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Test Data Document:
94117-314025 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification formation
excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental
and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
16 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: